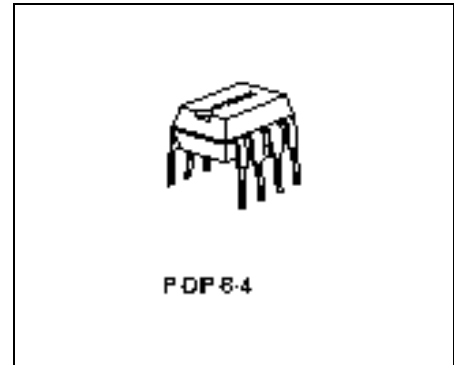


1 Overview

1.1 Features

- Optimized for headlight beam control applications
- Delivers up to 0.8 A
- Low saturation voltage;
typ. 1.2 V total @ 25 °C; 0.4 A
- Output protected against short circuit
- Overtemperature protection with hysteresis
- Over- and undervoltage lockout
- No crossover current
- Internal clamp diodes



1.2 Description

The TLE 4209 is a fully protected H-Bridge Driver designed specifically for automotive headlight beam control and industrial servo control applications.

The part is built using Infineons bipolar high voltage power technology DOPL.

The device is available in a P-DIP-8-4 package.

The servo-loop-parameter pos.- and neg. Hysteresis, pos.- and neg. deadband and angle-amplification are programmable with external resistors.

An internal window-comparator controls the input line. In the case of a fault condition, like short circuit to GND, short circuit to supply-voltage, and broken wire, the TLE 4209 stops the motor immediately (brake condition).

Furthermore the built in features like over- and undervoltage-lockout, short-circuit-protection and over-temperature-protection will open a wide range of automotive- and industrial applications.

| Type | Package |
|----------|-----------|
| TLE 4209 | P-DIP-8-4 |

1.3 Pin Definitions and Functions

| Pin No. | Symbol | Function |
|------------------|--------|----------------------|
| P-DIP-8-4 | | |
| 1 | FB | Feedback Input |
| 2 | HYST | Hysteresis I/O |
| 3 | OUT1 | Power Output 1 |
| 4 | V_S | Power Supply Voltage |
| 5 | OUT2 | Power Output 2 |
| 6 | GND | Ground |
| 7 | RANGE | Range Input |
| 8 | REF | Reference Input |

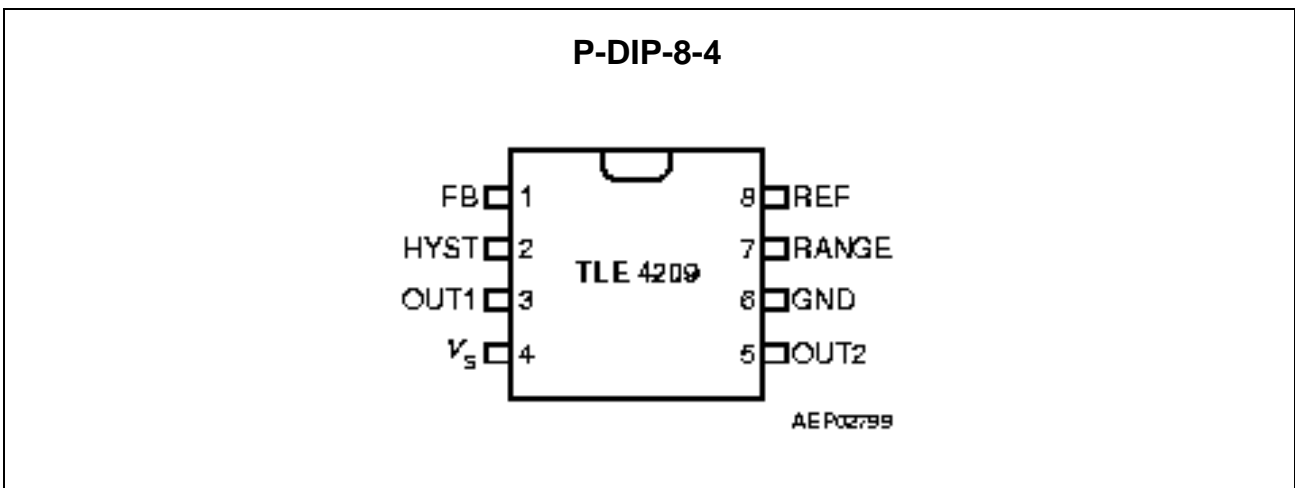


Figure 1 Pin Configuration (top view)

1.4 Functional Block Diagram

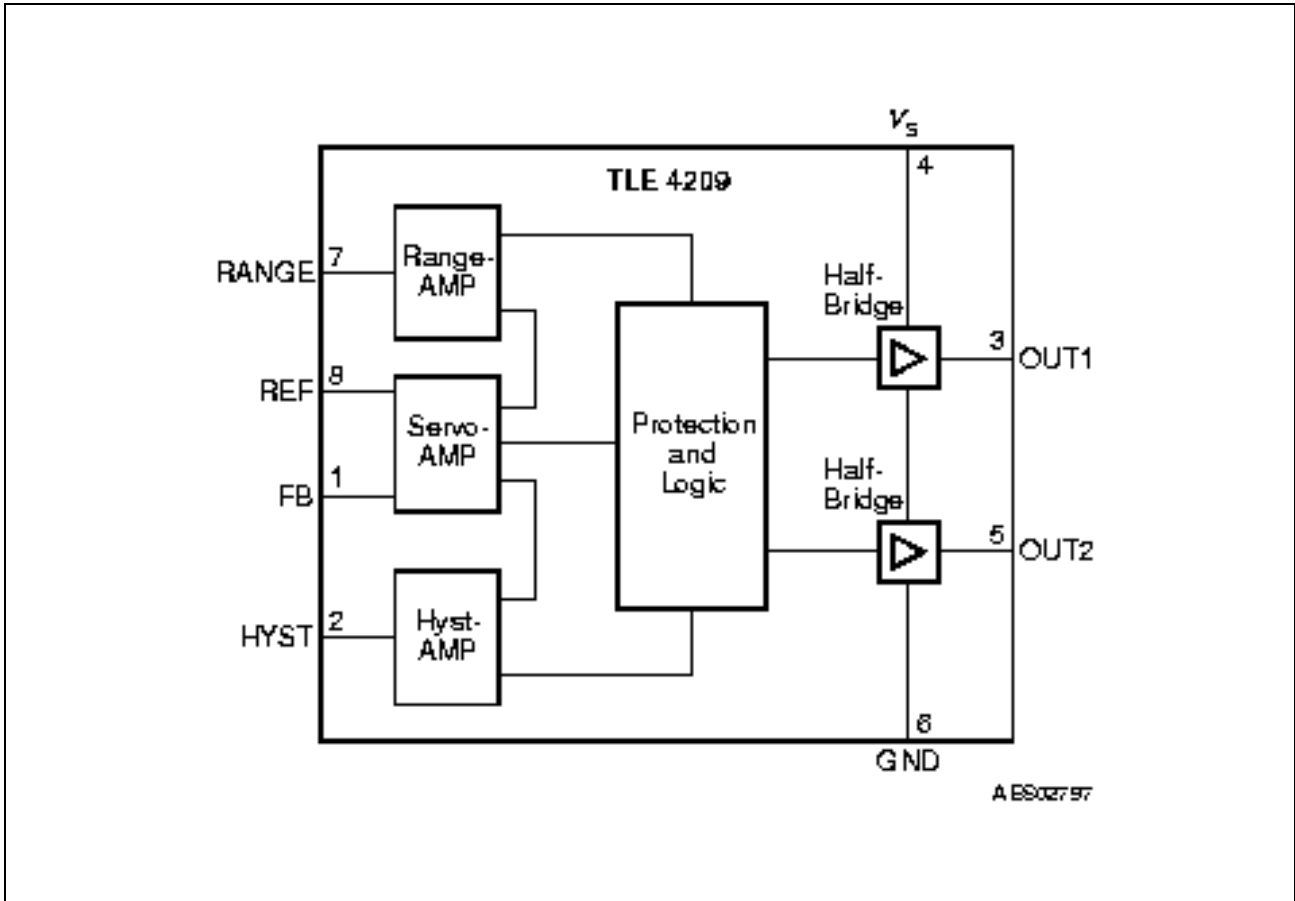


Figure 2 Block Diagram

1.5 Absolute Maximum Ratings

| Parameter | Symbol | Limit Values | | Unit | Remarks |
|-----------|--------|--------------|------|------|---------|
| | | min. | max. | | |

Voltages

| | | | | | |
|--|-------|-------|----|---|--|
| Supply voltage | V_S | - 0.3 | 45 | V | - |
| Supply voltage | V_S | - 1 | - | V | $t < 0.5 \text{ s}; I_S > - 2 \text{ A}$ |
| Logic input voltages (FB, REF, RANGE, HYST) | V_I | - 0.3 | 20 | V | - |

Currents

| | | | | | |
|---|-----------|------------|--------|----------|-------------------------------|
| Output current (OUT1, OUT2) | I_{OUT} | - | - | A | internally limited |
| Output current (Diode) | I_{OUT} | - 1 | 1 | A | - |
| Input current (FB, REF, RANGE, HYST) | I_{IN} | - 2 - 6 | 2 6 | mA mA | $t < 2 \text{ ms}; t/T < 0.1$ |

Temperatures

| | | | | | |
|----------------------|-----------|------|-----|----|---|
| Junction temperature | T_j | - 40 | 150 | °C | - |
| Storage temperature | T_{stg} | - 50 | 150 | °C | - |

Thermal Resistances

| | | | | | |
|------------------------------|------------|--|-----|-----|---|
| Junction ambient (P-DIP-8-4) | R_{thjA} | | 100 | K/W | - |
|------------------------------|------------|--|-----|-----|---|

Note: Stresses above those listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

1.6 Operating Range

| Parameter | Symbol | Limit Values | | Unit | Remarks |
|---------------------------|--------------|--------------|---------------|-------------|---------------------------------------|
| | | min. | max. | | |
| Supply voltage | V_S | 8 | 18 | V | After V_S rising above $V_{UV\ ON}$ |
| Supply voltage increasing | V_S | - 0.3 | $V_{UV\ ON}$ | V | Outputs in tristate |
| Supply voltage decreasing | V_S | - 0.3 | $V_{UV\ OFF}$ | V | Outputs in tristate |
| Output current | I_{OUT1-2} | - 0.8 | 0.8 | A | - |
| Input current (FB, REF) | I_{IN} | - 50 | 500 | μA | - |
| Junction temperature | T_j | - 40 | 150 | $^{\circ}C$ | - |

Note: In the operating range, the functions given in the circuit description are fulfilled.

1.7 Electrical Characteristics

$8\ V < V_S < 18\ V$; $I_{OUT1-2} = 0\ A$; $-40\ ^{\circ}C < T_j < 150\ ^{\circ}C$ (unless otherwise specified)

| Parameter | Symbol | Limit Values | | | Unit | Test Condition |
|-----------|--------|--------------|------|------|------|----------------|
| | | min. | typ. | max. | | |

Current Consumption

| | | | | | | |
|----------------|-------|---|----|----|----|---|
| Supply current | I_S | - | 12 | 20 | mA | - |
| Supply current | I_S | - | 20 | 30 | mA | $I_{OUT1} = 0.4\ A$ $I_{OUT2} = -0.4\ A$ |
| Supply current | I_S | - | 30 | 50 | mA | $I_{OUT1} = 0.8\ A$ $I_{OUT2} = -0.8\ A$ |

Over- and Under Voltage Lockout

| | | | | | | |
|-----------------------|---------------|------|------|----|---|----------------------------|
| UV Switch ON voltage | $V_{UV\ ON}$ | - | 7.4 | 8 | V | V_S increasing |
| UV Switch OFF voltage | $V_{UV\ OFF}$ | 6.3 | 6.9 | - | V | V_S decreasing |
| UV ON/OFF Hysteresis | V_{UVHY} | - | 0.5 | - | V | $V_{UV\ ON} - V_{UV\ OFF}$ |
| OV Switch OFF voltage | $V_{OV\ OFF}$ | - | 20.5 | 23 | V | V_S increasing |
| OV Switch ON voltage | $V_{OV\ ON}$ | 17.5 | 20 | - | V | V_S decreasing |
| OV ON/OFF Hysteresis | V_{OVHY} | - | 0.5 | - | V | $V_{OV\ OFF} - V_{OV\ ON}$ |

1.7 Electrical Characteristics (cont'd)
 $8\text{ V} < V_S < 18\text{ V}; I_{\text{OUT}1-2} = 0\text{ A}; -40\text{ }^\circ\text{C} < T_j < 150\text{ }^\circ\text{C}$ (unless otherwise specified)

| Parameter | Symbol | Limit Values | | | Unit | Test Condition |
|-----------|--------|--------------|------|------|------|----------------|
| | | min. | typ. | max. | | |

Outputs OUT1-2
Saturation Voltages

| | | | | | | |
|--|--------------------|---|------|------|---|----------------------------------|
| Source (upper) $I_{\text{OUT}} = -0.2\text{ A}$ | $V_{\text{SAT U}}$ | – | 0.85 | 1.15 | V | $T_j = 25\text{ }^\circ\text{C}$ |
| Source (upper) $I_{\text{OUT}} = -0.4\text{ A}$ | $V_{\text{SAT U}}$ | – | 0.90 | 1.20 | V | $T_j = 25\text{ }^\circ\text{C}$ |
| Sink (upper) $I_{\text{OUT}} = -0.8\text{ A}$ | $V_{\text{SAT U}}$ | – | 1.10 | 1.50 | V | $T_j = 25\text{ }^\circ\text{C}$ |
| Sink (lower) $I_{\text{OUT}} = 0.2\text{ A}$ | $V_{\text{SAT L}}$ | – | 0.15 | 0.23 | V | $T_j = 25\text{ }^\circ\text{C}$ |
| Sink (lower) $I_{\text{OUT}} = 0.4\text{ A}$ | $V_{\text{SAT L}}$ | – | 0.25 | 0.40 | V | $T_j = 25\text{ }^\circ\text{C}$ |
| Sink (lower) $I_{\text{OUT}} = 0.8\text{ A}$ | $V_{\text{SAT L}}$ | – | 0.45 | 0.75 | V | $T_j = 25\text{ }^\circ\text{C}$ |

| | | | | | | | |
|------------|---------------------------------|------------------|---|-----|-----|---|--|
| Total drop | $I_{\text{OUT}} = 0.2\text{ A}$ | V_{SAT} | – | 1.0 | 1.4 | V | $V_{\text{SAT}} = V_{\text{SAT U}} + V_{\text{SAT L}}$ |
| Total drop | $I_{\text{OUT}} = 0.4\text{ A}$ | V_{SAT} | – | 1.2 | 1.7 | V | $V_{\text{SAT}} = V_{\text{SAT U}} + V_{\text{SAT L}}$ |
| Total drop | $I_{\text{OUT}} = 0.8\text{ A}$ | V_{SAT} | – | 1.6 | 2.5 | V | $V_{\text{SAT}} = V_{\text{SAT U}} + V_{\text{SAT L}}$ |

Clamp Diodes

| | | | | | | |
|------------------------|------------------|---|-----|-----|----|----------------------|
| Forward voltage; upper | V_{FU} | – | 1.0 | 1.5 | V | $I_F = 0.4\text{ A}$ |
| Upper leakage current | I_{LKU} | – | | 5 | mA | $I_F = 0.4\text{ A}$ |
| Forward voltage; lower | V_{FL} | – | 0.9 | 1.4 | V | $I_F = 0.4\text{ A}$ |

1.7 Electrical Characteristics (cont'd)
 $8\text{ V} < V_S < 18\text{ V}; I_{\text{OUT}1-2} = 0\text{ A}; -40\text{ }^\circ\text{C} < T_j < 150\text{ }^\circ\text{C}$ (unless otherwise specified)

| Parameter | Symbol | Limit Values | | | Unit | Test Condition |
|-----------|--------|--------------|------|------|------|----------------|
| | | min. | typ. | max. | | |

Input-Interface
Input REF

| | | | | | | |
|-------------------|-------------------|-----|-----|-----|------------|--|
| Quiescent voltage | $V_{\text{REF}q}$ | – | 200 | 240 | mV | $I_{\text{REF}} = 0\text{ }\mu\text{A}$ |
| Input resistance | R_{REF} | 4.5 | 6.0 | 7.5 | k Ω | $0\text{ V} < V_{\text{REF}} < 0.5\text{ V}$ |

Input FB

| | | | | | | |
|-------------------|------------------|-----|-----|-----|------------|---|
| Quiescent voltage | $V_{\text{FB}q}$ | – | 200 | 240 | mV | $I_{\text{FB}} = 0\text{ }\mu\text{A}$ |
| Input resistance | R_{FB} | 4.5 | 6.0 | 7.5 | k Ω | $0\text{ V} < V_{\text{FB}} < 0.5\text{ V}$ |

Input/Output HYST

| | | | | | | |
|--|------------------------|-------|------|-----|---------------|--|
| Current Offset | $I_{\text{HYSTIO}250}$ | – 2 | 0.35 | 3 | μA | $I_{\text{REF}} = I_{\text{FB}} = 250\text{ }\mu\text{A}$ $V_{\text{HYST}} = V_S / 2$ |
| | $I_{\text{HYSTIO}40}$ | – 1.3 | 0 | 1.3 | μA | $I_{\text{REF}} = I_{\text{FB}} = 40\text{ }\mu\text{A}$ $V_{\text{HYST}} = V_S / 2$ |
| Current Amplification $A_{\text{HYST}} = I_{\text{HYST}} / (I_{\text{REF}} - I_{\text{FB}})$ | A_{HYST} | 0.8 | 0.95 | 1.1 | – | $-20\text{ }\mu\text{A} < I_{\text{HYST}} < -10\text{ }\mu\text{A};$ $10\text{ }\mu\text{A} < I_{\text{HYST}} < 20\text{ }\mu\text{A};$ $I_{\text{REF}} = 250\text{ }\mu\text{A}$ $V_{\text{HYST}} = V_S / 2$ |
| Current Gain $G_{\text{HYST}} = (I_{\text{HYST}} - I_{\text{HYSTIO}40}) / (I_{\text{REF}} - I_{\text{FB}})$ | G_{HYST} | 0.8 | 0.95 | 1.1 | – | $I_{\text{HYST}} = \pm 2\text{ }\mu\text{A};$ $I_{\text{REF}} = 40\text{ }\mu\text{A};$ $V_{\text{HYST}} = V_S / 2$ |
| Threshold voltage High | V_{HYH} / V_S | 51 | 52 | 54 | % | – |
| Deadband voltage High | V_{DBH} / V_S | 50 | 50.4 | 51 | % | – |

1.7 Electrical Characteristics (cont'd)
 $8\text{ V} < V_S < 18\text{ V}; I_{\text{OUT}1-2} = 0\text{ A}; -40\text{ }^\circ\text{C} < T_j < 150\text{ }^\circ\text{C}$ (unless otherwise specified)

| Parameter | Symbol | Limit Values | | | Unit | Test Condition |
|-----------------------|------------------------|--------------|------|------|------|---|
| | | min. | typ. | max. | | |
| Deadband voltage Low | V_{DBL} / V_S | 49 | 49.6 | 50 | % | – |
| Threshold voltage Low | V_{HYL} / V_S | 46 | 48 | 49 | % | – |
| Hysteresis Window | V_{HYW} / V_S | 3.0 | 4.0 | 5.0 | % | $(V_{\text{HYH}} - V_{\text{HYL}}) / V_S$ |
| Deadband Window | V_{DBW} / V_S | 0.4 | 0.8 | 1.2 | % | $(V_{\text{DBH}} - V_{\text{DBL}}) / V_S$ |

Input RANGE

| | | | | | | |
|-------------------------|--------------------|------|-----|-----|---------------|---------------------------------------|
| Input current | I_{RANGE} | – 1 | – | 1 | μA | $0\text{ V} < V_{\text{RANGE}} < V_S$ |
| Switch-OFF voltage High | V_{OFFH} | – 25 | 0 | 100 | mV | refer to V_S |
| Switch-OFF voltage Low | V_{OFFL} | 300 | 400 | 500 | mV | refer to GND |

Thermal Shutdown

| | | | | | | |
|--|------------------|-----|-----|-----|------------------|---|
| Thermal shutdown junction temperature | T_{jSD} | 150 | 175 | 200 | $^\circ\text{C}$ | – |
| Thermal switch-on junction temperature | T_{jSO} | 120 | – | 170 | $^\circ\text{C}$ | – |
| Temperature hysteresis | ΔT | – | 30 | | K | – |

Note: The listed characteristics are ensured over the operating range of the integrated circuit. Typical characteristics specify mean values expected over the production spread. If not otherwise specified, typical characteristics apply at $T_A = 25\text{ }^\circ\text{C}$ and the given supply voltage.

2 Diagrams

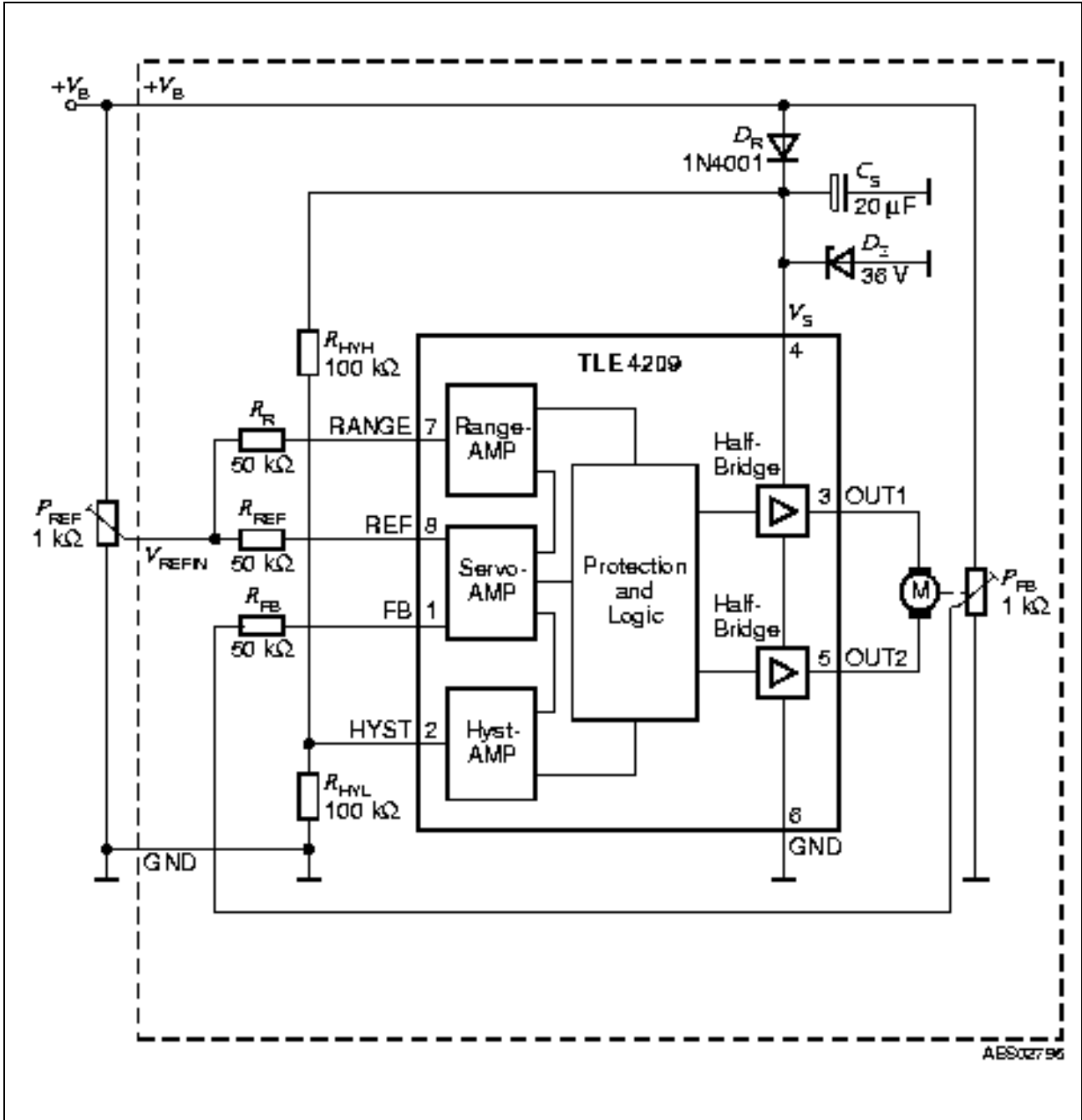


Figure 3 Application Circuit

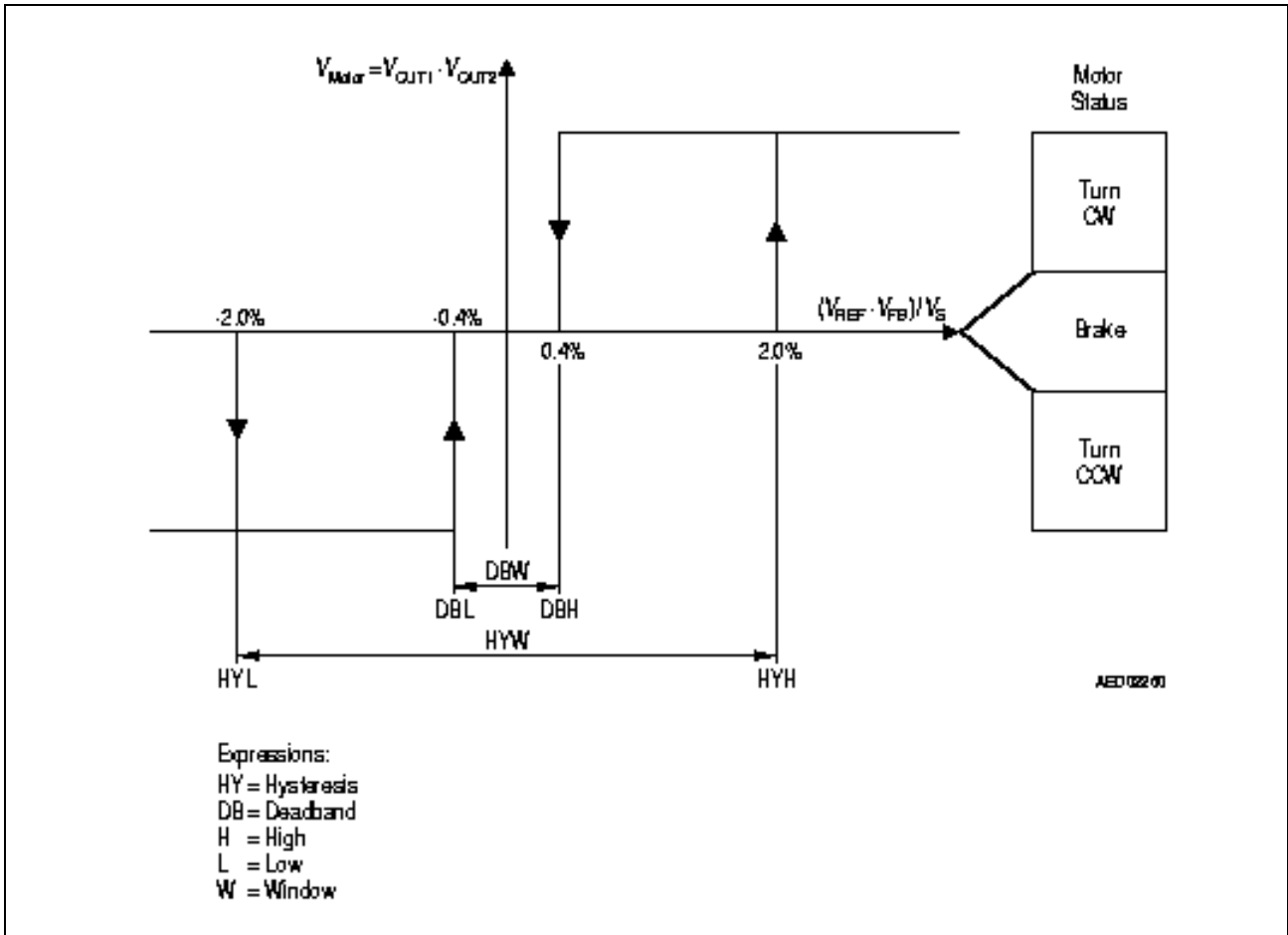


Figure 4 Hysteresis, Phaselag and Deadband-Definitions

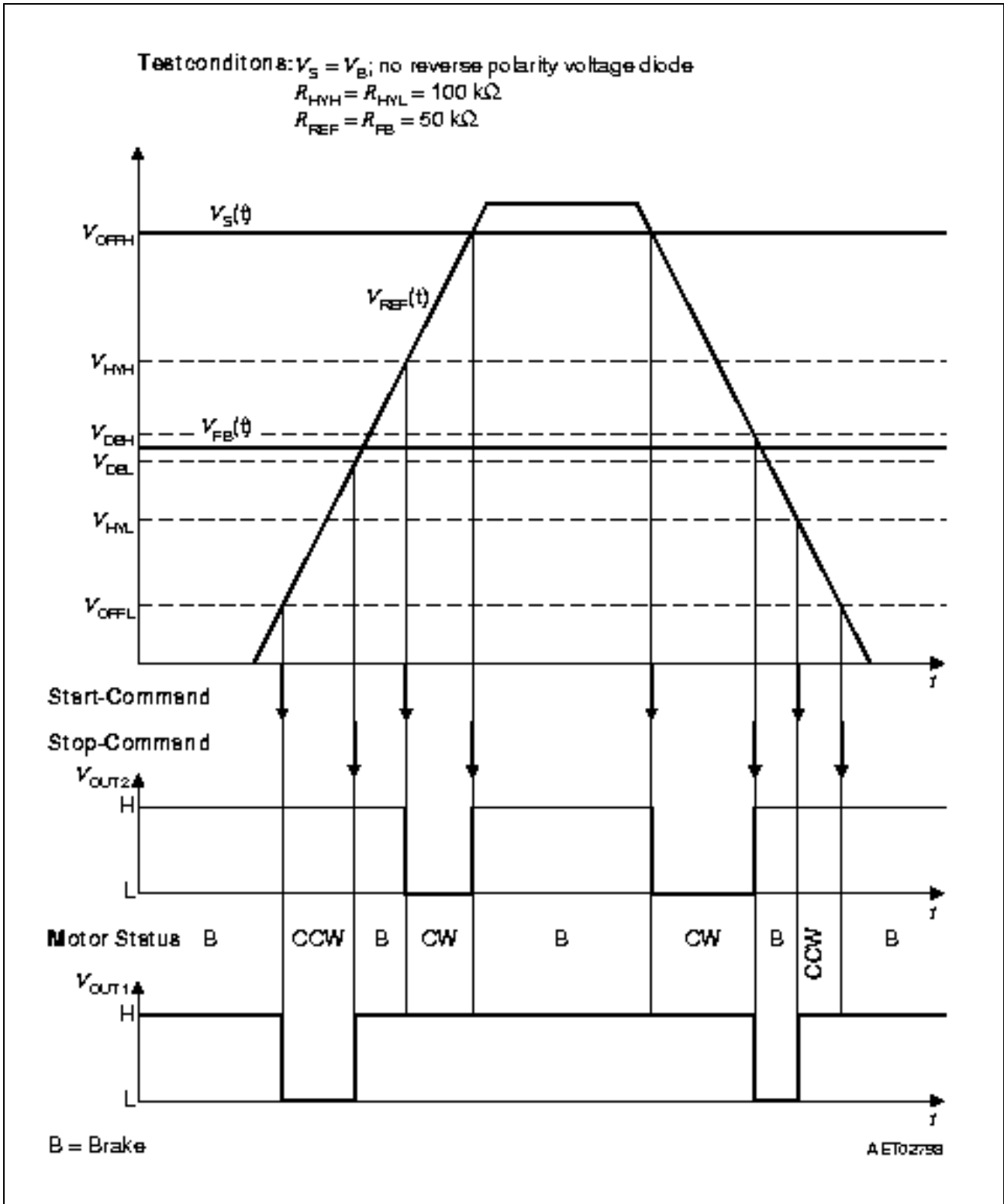
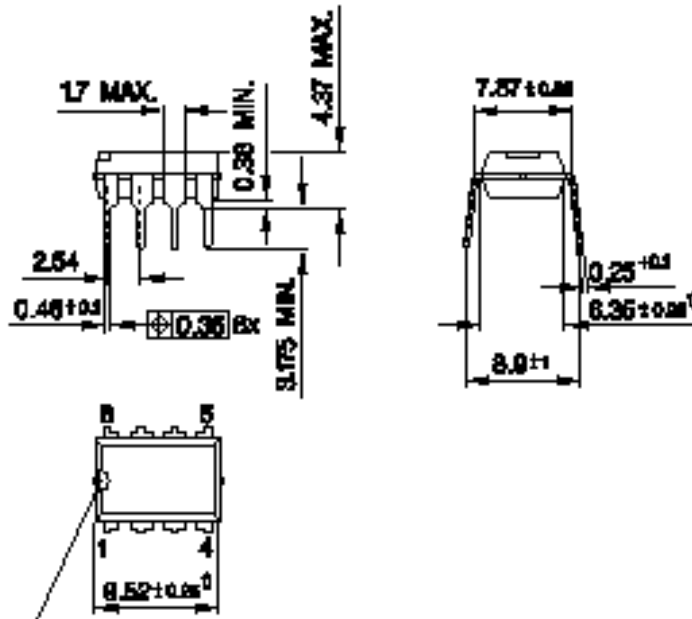


Figure 5 Timing and Phase-Lag

3 Package Outlines

P-DIP-8-4
(Plastic Dual In-line Package)



Index Marking

† Does not include plastic or metal protrusion of 0.25 max. per side

Sorts of Packing

Package outlines for tubes, trays etc. are contained in our Data Book "Package Information".

SMD = Surface Mounted Device

Dimensions in mm